Harnessing Photonic Integrated Circuits



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Photonic Devices



1969: 46 years of integrated optics ...





TOWARDS 2020 – PHOTONICS DRIVING ECONOMIC GROWTH IN EUROPE

Multiannual Strategic Roadmap 2014–2020



Photonics Research and Innovation Challenges

- Information & Communication 2.1
- Industrial Manufacturing & Quality 2.2
- Life Science & Health 2.3
- Emerging Lighting, Electronics & Displays 2.4
- Security, Metrology & Sensors 2.5
- Design and Manufacturing of Components & Systems 2.6
- Education, Training & Disruptive Research 2.7

Roadmaps







Integrated Photonic Systems Roadmap

Integrated photonics: towards ubiquitousness





- Moore law in photonics... No scaling in photonics !
- Photonics as electronics.... Photonics is analog !
- Plasmonic, graphene, quantum, ...
- CMOS Compatibility... Mendeleev on chip !
- More Moore or More than Moore? ... Integration, synergy
- Everyone does their job! ... generic foundry scheme
- Control & feedback, toward "system-on-a-chip" paradigm



Summary

Control layer motivations

Monitor (CLIPP)







Algorithms and techniques

Signal labelling techniques



Mode unscrambling









The generic foundry model





Control & Feedback: motivations



- Benefits of photonic integration lies in the aggregation of several components
- Technology can squeeze many devices in small chips



 Complex photonic systems-on-chip are still struggling to emerge...

Technology is critical...

High Index contrast technologies

 $\Delta T = 1 \text{ K} \rightarrow \Delta f = 10 \text{ GHz}$

 $\Delta n = 10^{-4} \rightarrow \Delta f = 10 \text{ GHz}$

 $\Delta w = 1 \text{ nm} \rightarrow \Delta f = 100 \text{ GHz}$

TE/TM and λ dependence...

(Interferometric) devices suffer from temperature drifts, xtalk, fabrication tolerances, nonlinearities, aging...

Control & Feedback: motivations



- Benefits of photonic integration lies in the aggregation of several components
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 Complex photonic systems-on-chir emerge...

Toward a "LESS"

FormatLESS

ContentsLESS

Latency

Tech ology is critical Silic tion f = 10 GHz $\rightarrow \Delta f = 10 \text{ GHz}$ f = 10 GHz f = 10 GHz f = 10 GHz f = 10 GHzf = 10 GHz

(Interferometric) devices suffer from temperature drifts, xtalk, fabrication tolerances, nonlinearities, aging...

| S | SS | DirectionLESS | ESS |
|------|------|---------------|-----|
| ost | Ļ | | |
| SS C | olor | Less space | rid |
| Г | Ŭ | Less energy | U |

Definition of "System"





Photonics needs feedback and control

Feedback controlled VLSI photonics





PICs: uncertainties and variability



... fabrication tolerances





Courtesy of IBM, 2007F. XIA, et al, Nat. Photonics, 2007Inm tolerance in waveguide width, 100 GHz wavelength shift

... stochastic nature of parameters





... temperature dependence

| Material | K _{th} [K ⁻¹] | $\Delta f/\Delta T$ [GHz K $^{-1}$] |
|------------------|------------------------------------|--------------------------------------|
| SiO ₂ | 10 ⁻⁵ | 1.5 |
| Si, InP, | 2 10-4 | 10 |

... operational conditions



PICs: adapting and programming



... non linear effects

Nonlinear frequency shift, Two photon Absorption



... programmable integrated photonics



Y. Shen et al, Nat Photonics 11 (2017)



D. Perez et al., Nat Communications 8:636 (2017)

... adaptive tuning and locking to "external" drifts





L. Zhuang et al., Optica **2** (2015)¹⁶

PICs: tuning and locking



Need for automatic procedures for tuning and locking









Automatic hitless reconfiguration of silicon photonics microring filters, F. Morichetti [10688-40]

The control layer





OPTICAL PROBES

- Non-perturbative (= test-pin)

ACTUATORS

- Tunable ('fast') for tuning, circuit control and adaptive reconfiguration through feedback signals
- **Permanent**, self holding to avoid to feed actuators. For programmable photonics and post fabrication trimming (fabrication tolerances compensation)
- (Non-) Reversible for programmable photonics (only once by foundry and/or final users or reprogrammable), trimming
- Analog / Digital circuit control / switches
- Amplitude / Phase
- Tuning /Trimming STRATEGY (control layer)

"Actuators" (for trimming) in literature

- FIB: C. Shu, 2003 (rib wg, birefringence, TE/TM coupling)
- e-beam: Ghent, 2008 (4.9 nm, Q decrease, strain in cladding)
- nano-oxidation: S. Mookherjea, 2011 (AFM tip)
- *Liquid crystals:* Gent, KIT, 2011, 2013 (80 V, 1 nm, complex)
- <u>femtosecond "ablation"</u>: Vien Van, 2011 (0.25J/cm², 10nm, reversible, low Q)
- *Polymer coating, UV irradiation*: some groups (stability, loss)



J. Schrauwen, OE 2008



Wout De Cort, JOSAB 2011





S. Mookherjea, OL 2011

An athermal and trimmable waveguide





e-beam lithography of an amorphous Silicon layer and As₂S₃ *evaporation Propagation loss: 3 dB/cm*

 As_2S_3 Band-gap wavelength \approx 550 nm (green)

Fluorinated Polymer top layer (negative thermooptic coefficient)

A collaboration between ...



PoliMi Glasgow U. U. Delaware Clemson U. MIT

An athermal and trimmable waveguide





10X reduced sensitivity to NL induced thermal shift

Trimming of fabrication imperfections





Heater: "The" actuator





| | SiO ₂ | Silicon |
|-----------------------------|-------------------------------------|-------------------------------------|
| Length | 1-3 mm | 10-50 μm |
| π shift | 300-400 mW | 10-20 mW |
| $\Delta n_{eff} / \Delta T$ | 1·10 ⁻⁵ °C ⁻¹ | 2·10 ⁻⁴ °C ⁻¹ |
| Response time | 1 ms | 10 μs |
| Crosstalk | high | low |

Actuators for Tuning, still a dream...





The control layer: monitor





Light monitors: Ge, InP, hybrid, monolithic...



On-chip photodetection is a mature technology but... power hungry and photon hungry!

Ge on Silicon





Silicon itself can be used for light detection in the near-IR



Surface state absorption (SSA) PDs

Photogeneration due to defect states at the edges of a c-waveguide (symmetry breaking & dangling bonds)







M.W. Geis et al., PTL 19(3), 2007

Defect State Absorption (DSA) PDs

Photogeneration by ion implantation into the Si lattice

- λ -range 1270 to 1740 nm, bandwidth > 20 GHz
- exploited also in carrier depletion silicon modulator

Light-waveguide interaction

Surface State Absorption

Energy

hν

- Surface states are located typically within the first two/three silicon atomic layers (≈ 1 nm)
- Intra-gap energy states create a free carrier and a corresponding recombination center



Light dependent waveguide surface



Waveguide electrical conductivity





The CLIPP concept



ContacLess Integrated Photonic Probe (CLIPP)



Contactless capacitive access to the waveguide

Measuring the SSA induced waveguide conductance change ΔG

through an ultrasensitive electric **detection circuit**



CLIPP performance







Performance match monitoring requirements:

- Compact size: *L* down to 25 μm
- Sensitivity down to -40 dBm
- 40 dB dynamic range
- Speed down to 20 μs
- Both TE/TM polarizations
- Arbitrary waveguide geometry (single-mode/multimode)
- No loss, no backreflection, no amplitude/phase perturbation, no need for doping



The Deep CLIPP





Sensitivity record with deep CLIPP



A transparent detector: the CLIPP concept

The James Watt Nonofabrication Centre

ContacLess Integrated Photonic Probe (CLIPP)





Contactless capacitive access to the waveguide

Measuring the SSA induced waveguide conductance change ∆G through a lock-in detection circuit





Multipoint on-chip monitoring





Indium Phosphide







Oclaro InP Straight Waveguide



What does non-invasive mean?





- Tiny resonant wavelength shift (55fm or 7MHz) \rightarrow negligible for resonators with Q up to 10⁶
- Effective index perturbation < 0.5 ppm (comparable to 3 mK thermal fluctuation)</p>
- No appreciable penalty on the quality of transmitted signals!

CLIPP assisted automated fiber alignment





Map of the fiber-to-waveguide coupling





- No need for an output collection fiber
- Light coupling independent of the PIC integrated onto the chip
- Compared with tap detectors is completely transparent when switched off
- Suitable also for grating coupler alignment

The control layer: electronic





The control layer from literature



Dithering, analog, Columbia Univ. 2014



K. Padmaraju, et al, JLT 32(3), 2014

MIT-Berkely-Boulder 2016



C. Sun, et al., JSSC, 51(4) <mark>2016</mark>

DWDM transmitter and receiver

Monolithic platform, commercial 45 nm CMOS SOI process

Bang-bang, digital 15 bits Oracle 2014



X. Zheng, Opt. Express, 22(10) 2014

Tuning (peak search, analog) + locking (bang-bang, digital)

HP 2016



K. Yu, et al., JSSC, 51(09) 2016

Integrating photonics with silicon nanoelectronics for the next generation of systems on a chip, Nature, 19 April 2018



Immunity to input leakage current variations



Electronic ASIC for CLIPP reading

- 7 channels
- 80 MHz analog bandwidth
- On-chip I/Q lock-in demodulators
- Output filters (-3dB BW = 100kHz)
- 40 fA/\sqrt{Hz} input noise (@500kHz)
- 16pS resolution @500kHz (BW=100kHz) with integrated filters and 1V stimulus
- **1.6pS resolution** @500kHz (BW=1kHz) with external filters and 1V stimulus
- P_{TOT} = 62mW (9mW per Channel @1.8V)





Assembly and control hardware



Electronic controlling board with heater drivers, CLIPP readout circuitry and embed FPGA controller



Quasi-planar transposer coupling to gratings with PM fibers



Label demodulation within FPGA

The control layer: algorithms and techniques





Mach-Zehnder stabilization, locking, tuning...







- Automatic tuning and locking of MZI
- Maximum/Minimum locking
- Any bias locking (Ratio O₁/O₂ set point)
- Local feedback loop
- No TEC needed

10

A. Annoni et al, JSTQE, 22(6) 2016



Electronic helps photonic





Ring stabilization, locking, tuning...





Handling multiple degrees of freedom



Control many degrees-of-freedom (DOFs) using a single monitoring point

Several DOFs simultaneously dithered at orthogonal frequencies generated from a discrete-multi-tone generator (DMT)









- Extract N derivatives vs dithering tones (gradient, Hessian matrix, ...)
- Estimation of **descent direction & step size** (gradient or Newton method)
- **Step size refinement** (e.g. Back-Trace-Line-Search)
- Bang-Bang techniques



Thermal distribution





Crossbar router - Lightpath tracking and control





Thermal crosstalk compensation with feedback



8x8 Si photonic switch matrix





Thermal crosstalk compensation with feedback



8x8 Si photonic switch matrix





Thermal crosstalk compensation with feedback



8x8 Si photonic switch matrix





The control layer: pilot tones (LABEL)





Pilot tones for wavelength monitor





Heater



Pilot tones for wavelength monitor



Heater

voltage

6

6

Heater

5

5

Heater power [mW]



 λ_1 identified Automatic tuning and locking at λ_1

Pilot tones for wavelength monitor





58

Heater power [mW]

Pilot tones enable control







Unscrambling light

(automated mode demux)

Unscrambling light





Integrated mode unscrambler











All-optical mode reconstruction





- the MZI mesh self-configures automatically and reset itself after significantly perturbing the mixing
- 4-mode automatic unscramble (< 20 dB residual cross-talk)</p>

 No tuning

 S₁₁

 S₁₁ + S₁₂

 S₁₁ + S₁₂ + S₁₃





4x10Gbit/s channel unscrambling





4x10 Gbit/s channel unscrambling





Extraction of Channel D from output port OUT1



Signal unscrambling



Frequency domain....

4-mixed signals



Unscrambled signal





Time domain....

- All the 10 Gbit/s channels are switched on
- Sequential tuning of the MIMO demux for the extraction of channel A



Mode sorting











0

0 0







How many tools are needed... !

- Advanced (statistical) analysis software tools (circuit simulator)
- Robust design techniques (design on tolerance)
- Statistical PDKs
- Characterization techniques
- Hitless monitors... CLIPP !!
- Algorithms: Tuning, Locking, Routing (non invasive, circuit dependent)
- Pilot tones (for wavelength, polarization, mode and circuit routing)

Integrated photonics: ubiquitousness and complexity to be controlled





Acknowledgments, many people behind !

Photonics Devices Group
F. Morichetti, S. Grillanda, A. Annoni, D. Melati, N. Peserico, A. Melloni
Innovative Integrated Instrumentation for the Nanoscience (I3N)
M. Carminati, P. Ciccarella. E. Gugliemli, G. Ferrari, M. Sampietro

M. Sorel, B. Holmes, C. Klitis, University of Glasgow, Glasgow, UK

James Watt Nanofabrication Center (University of Glasgow)

M. Nazarathy, J. Fisher Technion University, Haifa, Israel

H2020 ICT-Streams Project. http://www.ict-streams.eu/

A. Fincato, G. Chiaretti STmicroelectronics

ICT_FET EU Project **BBOI** Breaking the barriers of Optical Integration http://www.bboi.eu

Advanced control technologies for integrated optics (ACTIO) Fondazione Cariplo (grant 2016-0881)